



APPLICATION DATA SHEET

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Title of Invention	BIPOLAR JUNCTION TRANSISTOR AND FABRICATING METHOD		
Application Type : regular, utility Attorney Docket Number : NAUP0486USA4			
Correspondence address: Customer Number: 027765 			
Continuing Data: This is a Continuation-in-part of US application number 10/064,051, filed 2002-06-05 , now PENDING.			
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